

UNISONIC TECHNOLOGIES CO., LTD

2N7002W Preliminary Power MOSFET

300mA, 60V N-CHANNEL POWER MOSFET

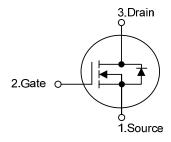
■ DESCRIPTION

The UTC **2N7002W** uses advanced technology to provide excellent $R_{\text{DS(ON)}}$, low gate charge and operation with low gate voltages. This device is suitable for use as a load switch or in PWM applications.

■ FEATURES

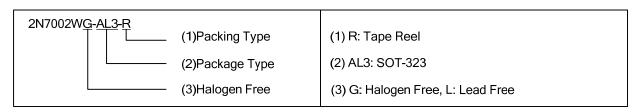
- * High Density Cell Design for Low R_{DS(ON)}.
- * Voltage Controlled Small Signal Switch
- * Rugged and Reliable
- * High Saturation Current Capability

■ SYMBOL

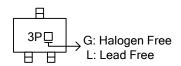


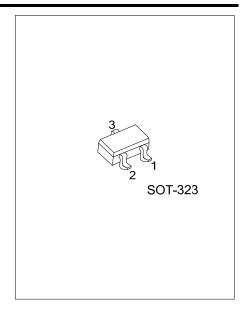
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking
Lead Free	Halogen Free	Package	1	2	3	Packing
2N7002WL-AL3-R	2N7002WG-AL3-R	SOT-323	S	G	D	Tape Reel



MARKING





■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C, unless otherwise specified.)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V_{DSS}	60	V	
Drain-Gate Voltage (R _{GS} ≤1MΩ)		V_{DGR}	60	V	
Gate Source Voltage	Continuous	\/	±20	V	
	Non Repetitive(t _P <50µs)	V_{GSS}	±40		
Drain Current	Continuous	-	300	mA	
Dialii Cuitelli	Pulsed	l _D	800		
Power Dissipation		D	200	mW	
Derated Above 25°C		P_D	1.6	mW/°C	
Junction Temperature		T_J	+ 150	°C	
Storage Temperature		T_{STG}	-55 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	625 (Note1)	°C/W	

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Drain-Source Breakdown Voltage	BV _{DSS}	V_{GS} =0V, I_D =10 μ A	60			V		
Drain-Source Leakage Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μΑ		
Gate-Source Leakage Current	I_{GSSF}	V _{GS} =20V, V _{DS} =0V			100	nA		
Gate-Source Leakage Current	I_{GSSR}	V_{GS} =-20V, V_{DS} =0V			-100	nA		
ON CHARACTERISTICS (Note2)								
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS} = V_{DS}$, $I_D = 250 \mu A$	1	2.1	2.5	V		
Drain-Source On-Voltage	V _{DS (ON)}	$V_{GS} = 10V, I_D = 300mA$	0.6 3.75		3.75	V		
Dialii-Source Oil-Voltage		$V_{GS} = 5.0V, I_{D} = 50mA$		0.09	1.5	v		
Static Drain-Source On-Resistance	D	V _{GS} =10V, I _D =300mA ,T _J =125°C			13.5	Ω		
Static Drain-Source On-Resistance	R _{DS} (ON)	V_{GS} =5.0V, I_D =50mA			7.5	Ω		
DYNAMIC CHARACTERISTICS								
Input Capacitance	C _{ISS}	V_{DS} =25V, V_{GS} =0V,f=1.0MHz		20	50	pF		
Output Capacitance	Coss			11	25	pF		
Reverse Transfer Capacitance	C _{RSS}			4	5	pF		
Turn-On Time	4	V_{DD} =30V, R_L =150 Ω , I_D =200mA,			20			
Turn-On Time	t _{ON}	V_{GS} =10V, R_{GEN} =25 Ω			20	nS		
Turn-Off Time	toff	V_{DD} =30V, R_L =25 Ω , I_D =200mA,			20	nS		
Turn-On Time	UOFF	V_{GS} =10V, R_{GEN} =25 Ω			20			
DRAIN-SOURCE DIODE CHARACTE	RISTICS AN	ID MAXIMUM RATINGS						
Drain-Source Diode Forward Voltage	V_{SD}	V _{GS} =0V, Is=300mA (Note)		0.88	1.5	V		
Maximum Pulsed Drain-Source Diode					0.8	Α		
Forward Current	I _{SM}				0.0			
Maximum Continuous Drain-Source Diode Forward Current	ls				300	mA		

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch. Minimum land pad size.

2. Pulse Test: Pulse Width≤300µs, Duty Cycle≤2.0%

TEST CIRCUIT AND WAVEFORM

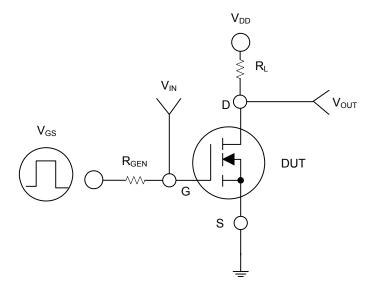


Fig. 1

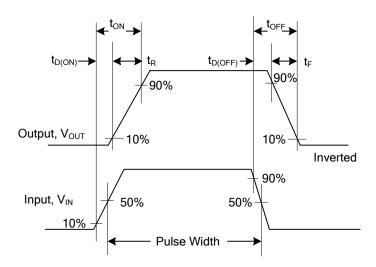


Fig. 2 Switching Waveforms

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